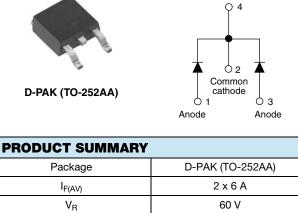
FREE

Vishay Semiconductors

Schottky Rectifier, 2 x 6 A



V_F at I_F

I_{RM}

T_J max.

Diode variation

 E_{AS}

Document Number: 93289

Revision: 03-Nov-10

Base common cathode

0.57 V

35 mA at 125 °C

150 °C

Common cathode

7 mJ

FEATURES

- Low forward voltage drop
- Guard ring for enhanced ruggedness and long term reliability
 Halogen-free according to JEC 61249-2-21
- Halogen-free according to IEC 61249-2-21 definition
- Popular D-PAK outline
- Center tap configuration
- Small foot print, surface mountable
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Compliant to RoHS Directive 2002/95/EC

DESCRIPTION

The VS-12CWQ06FN-M3 surface mount, center tap, Schottky rectifier series has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS	VALUES	UNITS						
I _{F(AV)}	Rectangular waveform	12	A						
V _{RRM}		60	V						
I _{FSM}	t _p = 5 μs sine	320	A						
V _F	6 Apk, T _J = 125 °C (per leg)	0.57	V						
TJ	Range	- 55 to 150	۵°C						

VOLTAGE RATINGS									
PARAMETER	SYMBOL	VS-12CWQ06FN-M3	UNITS						
Maximum DC reverse voltage	V _R	60	V						
Maximum working peak reverse voltage	V _{RWM}	00	v						

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST CONDI	TIONS	VALUES	UNITS				
Maximum average per leg		50 % duty cycle at T _C = 131 °C, rectangular waveform		6	A				
See fig. 5 per device	I _{F(AV)}	30% duty cycle at $T_{\rm C} = 131\%$ C	12						
Maximum peak one cycle		5 µs sine or 3 µs rect. pulse Following any rated		320	•				
non-repetitive surge current See fig. 7	I _{FSM}		rated V_{RRM} applied	105	A				
Non-repetitive avalanche energy per leg	E _{AS}	T _J = 25 °C, I _{AS} = 1.2 A, L = 10 mH		7	mJ				
Repetitive avalanche current per leg	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		0.8	А				



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ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS					
		6 A	T 05 %C	0.61				
Maximum forward	V _{FM} ⁽¹⁾	12 A	T _J = 25 °C	0.79				
voltage drop per leg See fig. 1	VFM ()	6 A	T 105 %C	0.57	V			
		12 A	T _J = 125 °C	0.72				
Maximum reverse leakage current per leg	I _{RM} ⁽¹⁾	T _J = 25 °C	$V_{B} = Rated V_{B}$	3	mA			
See fig. 2		T _J = 125 °C	V _R = naleu V _R	35				
Threshold voltage	V _{F(TO)}	$T_J = T_J$ maximum		0.36	V			
Forward slope resistance	r _t			24.14	mΩ			
Typical junction capacitance per leg	CT	$V_{R} = 5 V_{DC}$, (test signal ran	360	pF				
Typical series inductance per leg	L _S	Measured lead to lead 5 n	5.0	nH				

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 $\,\%$

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction and storage temperature range		T_{J} ⁽¹⁾ , T_{Stg}		- 55 to 150	°C			
Maximum thermal resistance,	per leg	Р	DC operation See fig. 4	3.0	°C/W			
junction to case	per device	R _{thJC}		1.5				
Approximate weight				0.3	g			
				0.01	oz.			
Marking device			Case style D-PAK (similar to TO-252AA)	12CW0	206FN			

Note

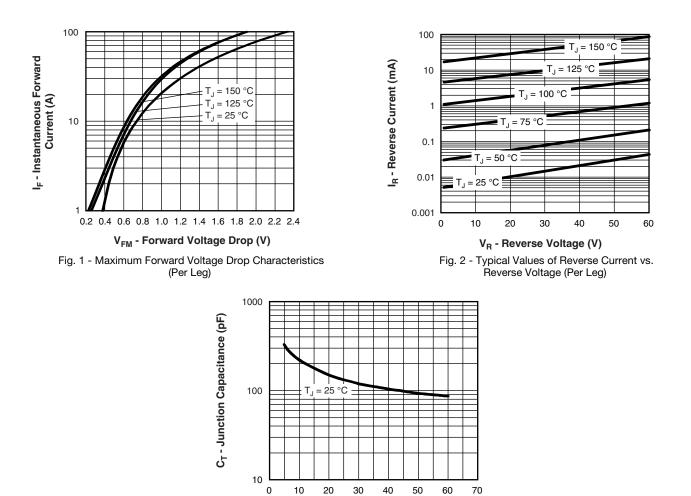
(1) $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$ thermal runaway condition for a diode on its own heatsink



VS-12CWQ06FN-M3

Schottky Rectifier, 2 x 6 A

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V_R - Reverse Voltage (V) Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

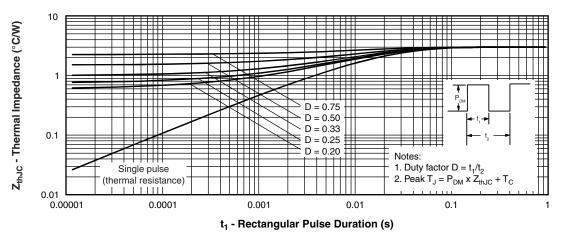


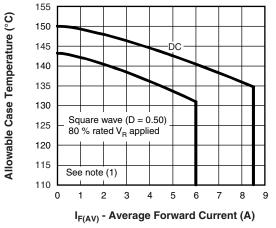
Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

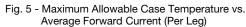
VS-12CWQ06FN-M3

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Schottky Rectifier, 2 x 6 A







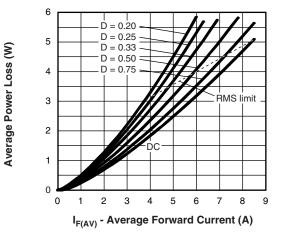


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

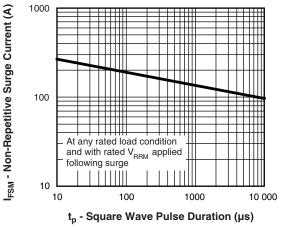


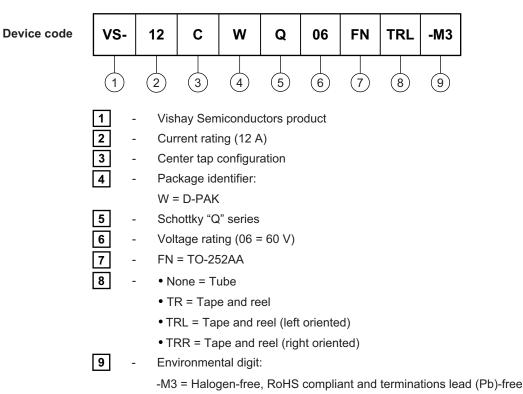
Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

Note

- ⁽¹⁾ Formula used: $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$;
- $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \ x \ \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see fig. 6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \ x \ \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$



ORDERING INFORMATION TABLE



ORDERING INFORMATION (Example)										
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION							
VS-12CWQ06FN-M3	75	3000	Antistatic plastic tube							
VS-12CWQ06FNTR-M3	2000	2000	13" diameter reel							
VS-12CWQ06FNTRL-M3	3000	3000	13" diameter reel							
VS-12CWQ06FNTRR-M3	3000	3000	13" diameter reel							

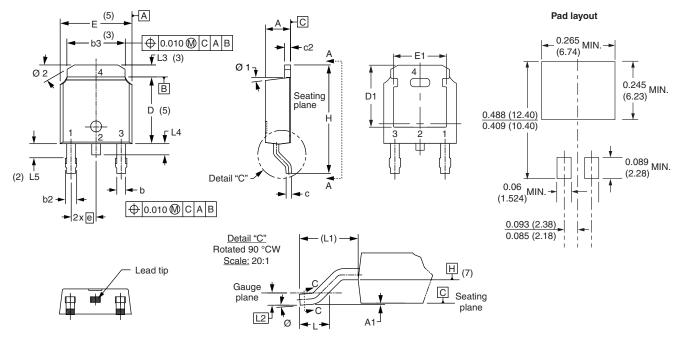
LINKS TO RELATED DOCUMENTS							
Dimensions www.vishay.com/doc?95016							
Part marking information	www.vishay.com/doc?95176						
Packaging information	www.vishay.com/doc?95033						
SPICE model	www.vishay.com/doc?95278						



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D-PAK (TO-252AA)

DIMENSIONS in millimeters and inches



SYMBOL	MILLIN	MILLIMETERS		INCHES		NOTES	NOTES		MILLIN	IETERS	INC	HES	NOTES
STINIBUL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
А	2.18	2.39	0.086	0.094			е	2.29	BSC	0.090	BSC		
A1	-	0.13	-	0.005			Н	9.40	10.41	0.370	0.410		
b	0.64	0.89	0.025	0.035			L	1.40	1.78	0.055	0.070		
b2	0.76	1.14	0.030	0.045			L1	2.74	BSC	0.108	REF.		
b3	4.95	5.46	0.195	0.215	3		L2	0.51	BSC	0.020	BSC		
с	0.46	0.61	0.018	0.024			L3	0.89	1.27	0.035	0.050	3	
c2	0.46	0.89	0.018	0.035			L4	-	1.02	-	0.040		
D	5.97	6.22	0.235	0.245	5		L5	1.14	1.52	0.045	0.060	2	
D1	5.21	-	0.205	-	3		Ø	0°	10°	0°	10°		
E	6.35	6.73	0.250	0.265	5		Ø1	0°	15°	0°	15°		
E1	4.32	-	0.170	-	3		Ø2	25°	35°	25°	35°		

Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽²⁾ Lead dimension uncontrolled in L5

⁽³⁾ Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad

⁽⁴⁾ Section C - C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip

(5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

⁽⁶⁾ Dimension b1 and c1 applied to base metal only

⁽⁷⁾ Datum A and B to be determined at datum plane H

⁽⁸⁾ Outline conforms to JEDEC outline TO-252AA

Document Number: 95016



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